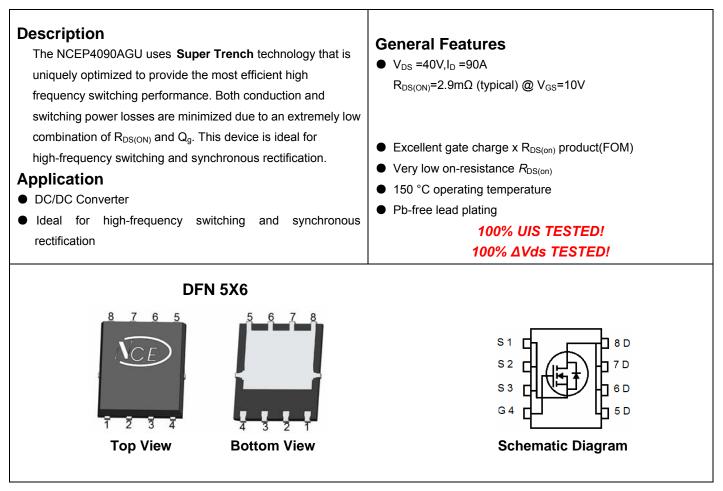


NCE N-Channel Super Trench Power MOSFET



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P4090AGU	NCEP4090AGU	DFN5x6-8L	-	-	-

Absolute Maximum Ratings (T_c=25[°]C unless otherwise noted)

Symbol	Limit	Unit
Vds	40	V
Vgs	±20	V
Ι _D	90	A
I _D (100℃)	63.6	А
I _{DM}	360	А
PD	70	W
	0.56	W/℃
E _{AS}	500	mJ
TJ,TSTG	-55 To 150	°C
R _{θJC}	1.8	°C/W
	VDS VGS ID ID(100°C) IDM PD EAS TJ,TSTG	VDS 40 VGS ±20 ID 90 ID(100°C) 63.6 IDM 360 PD 70 0.56 EAS TJ,TSTG -55 TO 150



Electrical Characteristics (T_c=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	40		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	····					<u>.</u>
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.0	3.0	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	2.9	3.4	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =20A		60	-	S
Dynamic Characteristics (Note4)	····					<u>.</u>
Input Capacitance	C _{lss}		-	1695	-	PF
Output Capacitance	C _{oss}	V _{DS} =20V,V _{GS} =0V, F=1.0MHz	-	840	-	PF
Reverse Transfer Capacitance	C _{rss}		-	34	-	PF
Switching Characteristics (Note 4)	····					<u>.</u>
Turn-on Delay Time	t _{d(on)}	V _{DD} =20V,I _D =20A V _{GS} =10V,R _G =1.6Ω	-	7.5	-	nS
Turn-on Rise Time	tr		-	4.0	-	nS
Turn-Off Delay Time	t _{d(off)}		-	37	-	nS
Turn-Off Fall Time	t _f		-	7.5	-	nS
Total Gate Charge	Qg	V 00V/1 00A	-	28	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=20V, I_{D}=20A,$	-	9.1		nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	5.8		nC
Drain-Source Diode Characteristics				•		
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	90	А
Reverse Recovery Time	t _{rr}	T_J = 25°C, I_F = I_S	-	14	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	21	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, t ≤ 10 sec.

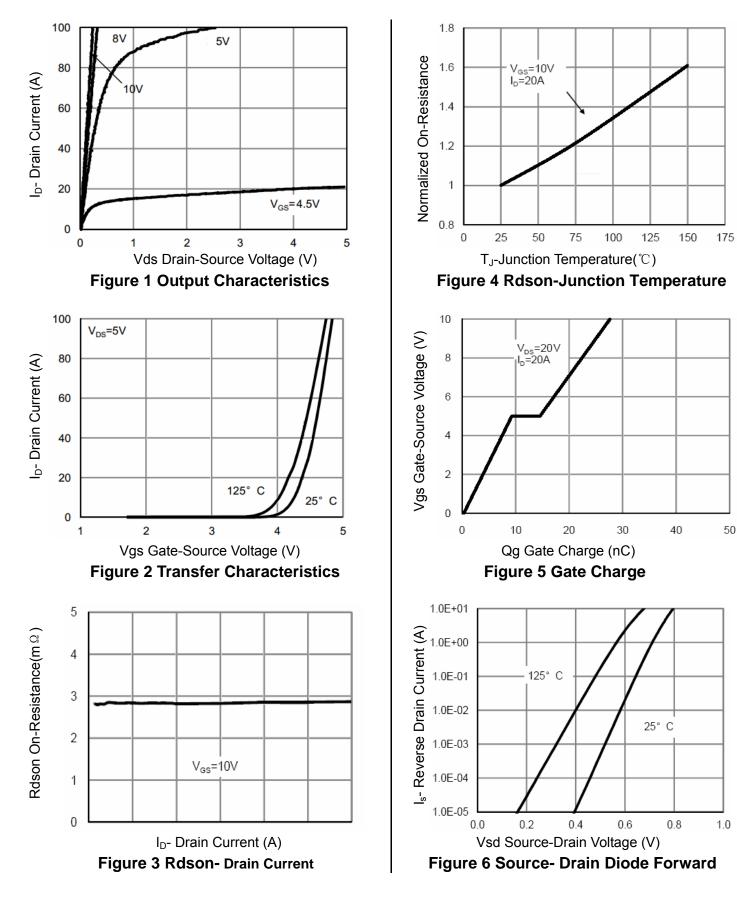
3. Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ \!\! \mathbb{C}$,V_DD=20V,V_G=10V,L=0.5mH,Rg=25 Ω



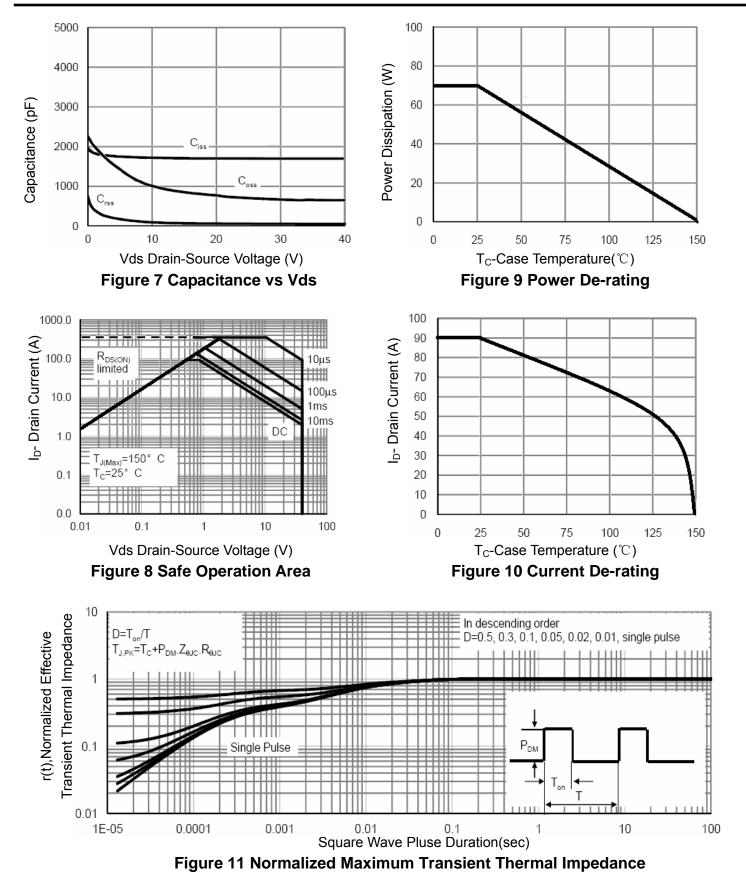
Typical Electrical and Thermal Characteristics





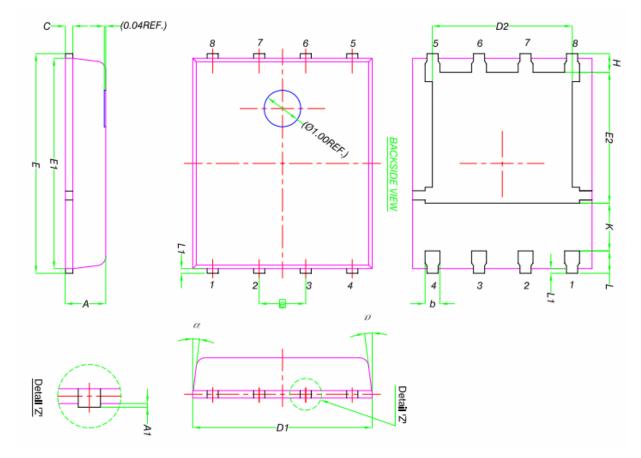
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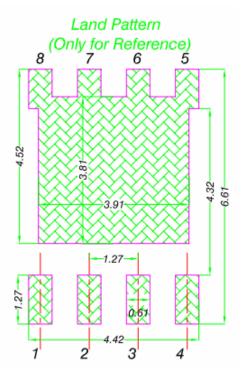




DFN5X6-8L Package Information



	MILLIMETERS				
DIM.	MIN.	NOM.	MAX.		
А	0.90	1.00	1.10		
A1	0	-	0.05		
b	0.33	0.41	0.51		
С	0.20	0.25	0.30		
D1	4.80	4.90	5.00		
D2	3.61	3.81	3.96		
E	5.90	6.00	6.10		
E1	5.70	5.75	5.80		
E2	3.38	3.58	3.78		
е	1.27 BSC				
Н	0.41	0.51	0.61		
К	1.10	-	-		
L	0.51	0.61	0.71		
L1	0.06	0.13	0.20		
α	0°	-	12°		





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